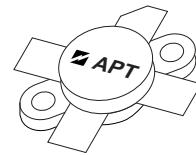
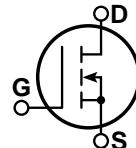




ARF520



RF POWER MOSFET

N-CHANNEL ENHANCEMENT MODE

165 V 150 W 100 MHz

The ARF520 is an RF power transistor designed for high voltage operation in narrow band ISM and MRI power amplifiers up to 100 MHz.

- Specified 125 Volt, 81 MHz Characteristics:

Output Power = 150 Watts.

Gain = 13dB (Class AB)

Efficiency = 50%

- High Voltage Breakdown and Large SOA for Superior Ruggedness.
- Industry standard package
- Low V_{th} thermal coefficient

MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	ARF520	UNIT
V_{DSS}	Drain-Source Voltage	500	Volts
I_D	Continuous Drain Current @ $T_C = 25^\circ\text{C}$	10	Amps
V_{GS}	Gate-Source Voltage	± 30	Volts
P_D	Total Device Dissipation @ $T_C = 25^\circ\text{C}$	250	Watts
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 200	$^\circ\text{C}$
T_L	Lead Temperature: 0.063" from Case for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage ($V_{GS} = 0\text{V}$, $I_D = 250\ \mu\text{A}$)	500			Volts
$V_{DS(ON)}$	On State Drain Voltage ① ($I_{D(ON)} = 5\text{A}$, $V_{GS} = 10\text{V}$)			4	
I_{DSS}	Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}$, $V_{GS} = 0\text{V}$)			25	μA
	Zero Gate Voltage Drain Current ($V_{DS} = 50\text{V}$, $V_{GS} = 0$, $T_C = 125^\circ\text{C}$)			250	
I_{GSS}	Gate-Source Leakage Current ($V_{GS} = \pm 30\text{V}$, $V_{DS} = 0\text{V}$)			± 100	nA
g_{fs}	Forward Transconductance ($V_{DS} = 25\text{V}$, $I_D = 5\text{A}$)	4	6		mhos
$V_{GS(TH)}$	Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 50\text{mA}$)	3		5	Volts

THERMAL CHARACTERISTICS

Symbol	Characteristic	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to Case			0.7	$^\circ\text{C/W}$
$R_{\theta CS}$	Case to Sink (Use High Efficiency Thermal Joint Compound and Planar Heat Sink Surface.)		0.1		

CAUTION: These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

APT Website - <http://www.advancedpower.com>

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C_{iss}	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 50V$ $f = 1\text{ MHz}$		800	1200	pF
C_{oss}	Output Capacitance			140	200	
C_{rss}	Reverse Transfer Capacitance			9	12	
$t_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$ $V_{DD} = 0.5 V_{DSS}$ $I_D = I_{D[\text{Cont.}]} @ 25^\circ C$ $R_G = 1.6 \Omega$		5.1	10	ns
t_r	Rise Time			4.1	8	
$t_{d(off)}$	Turn-off Delay Time			12.8	20	
t_f	Fall Time			4.0	8	

FUNCTIONAL CHARACTERISTICS (Push-Pull Configuration)

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
G_{PS}	Common Source Amplifier Power Gain	$f = 81\text{MHz}$ $I_{dq} = 50\text{mA}$ $V_{DD} = 125V$ $P_{out} = 150W$	13	14		dB
η	Drain Efficiency		50	55		%
Ψ	Electrical Ruggedness VSWR 5:1		No Degradation in Output Power			

① Pulse Test: Pulse width < 380 μs , Duty Cycle < 2%.

APT Reserves the right to change, without notice, the specifications and information contained herein.

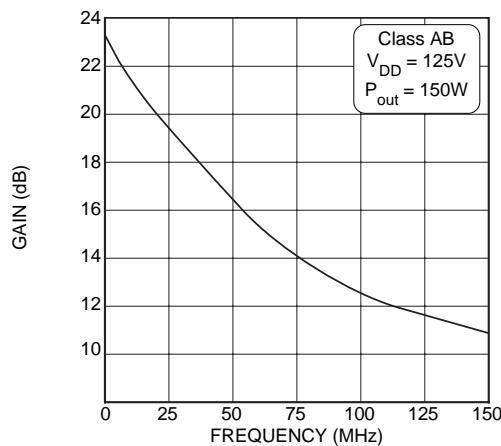


Figure 1, Typical Gain vs. Frequency

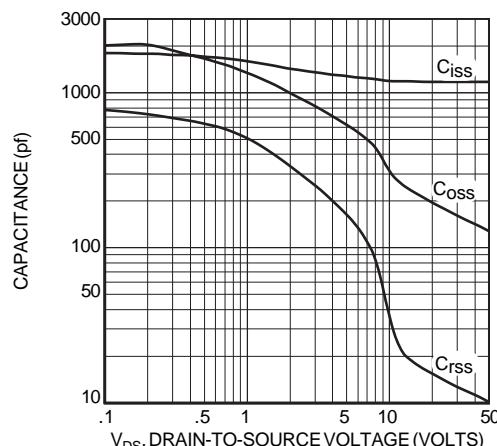


Figure 2, Typical Capacitance vs. Drain-to-Source Voltage

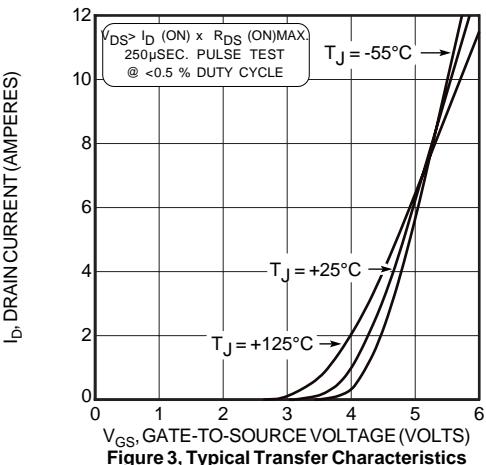


Figure 3, Typical Transfer Characteristics

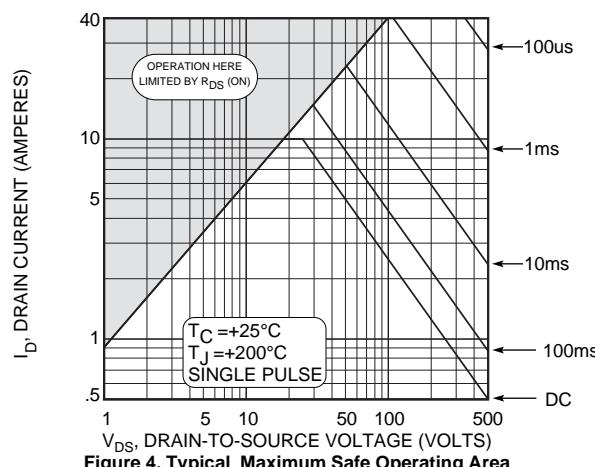


Figure 4, Typical Maximum Safe Operating Area

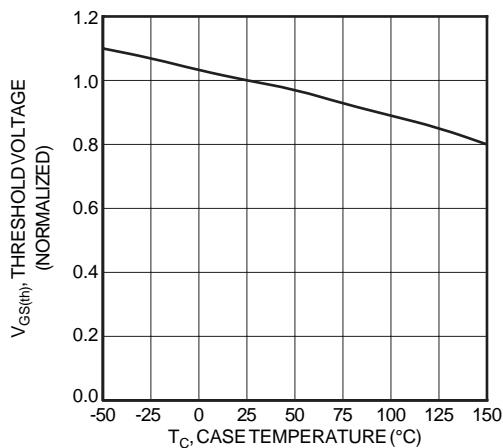


Figure 5, Typical Threshold Voltage vs Temperature

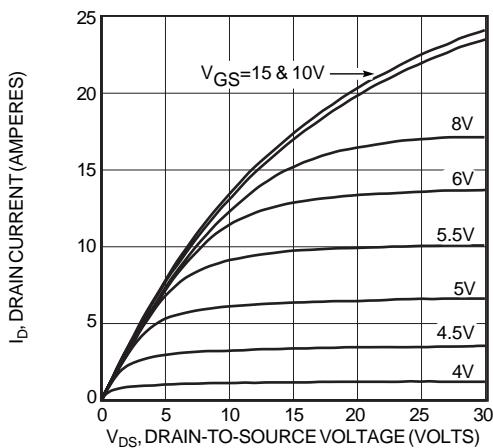


Figure 6, Typical Output Characteristics

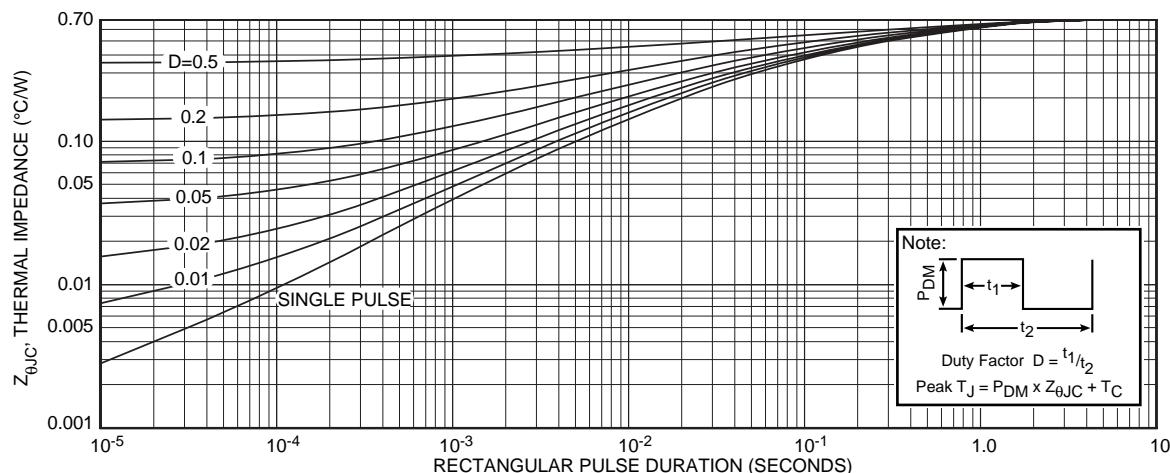


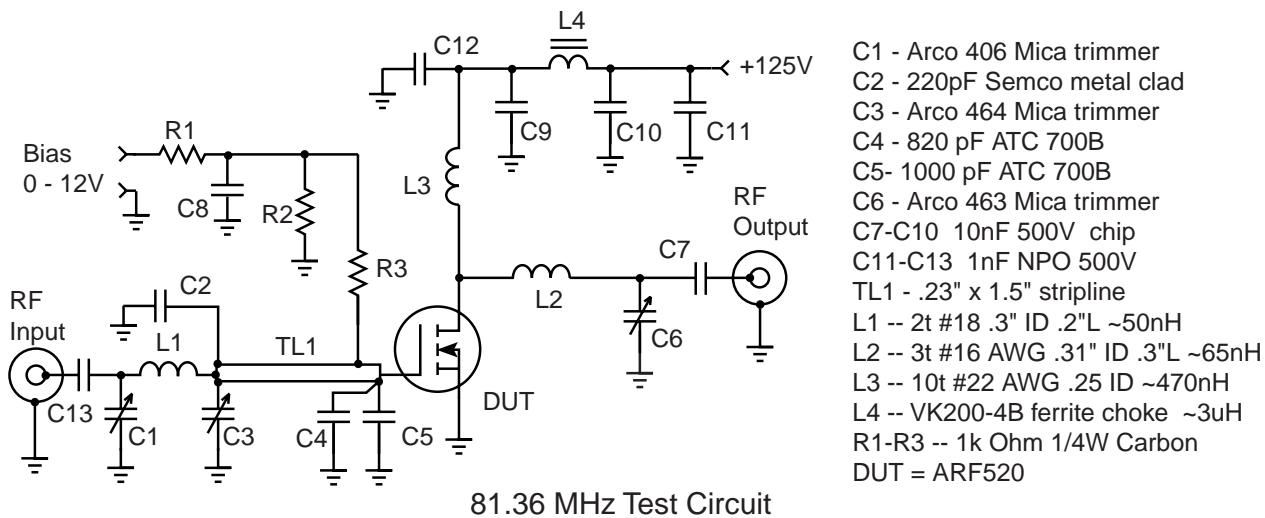
Figure 7, Maximum Effective Transient Thermal Impedance, Junction-to-Case vs. Pulse Duration

Table 1 - Typical Class AB Large Signal Input - Output Impedance

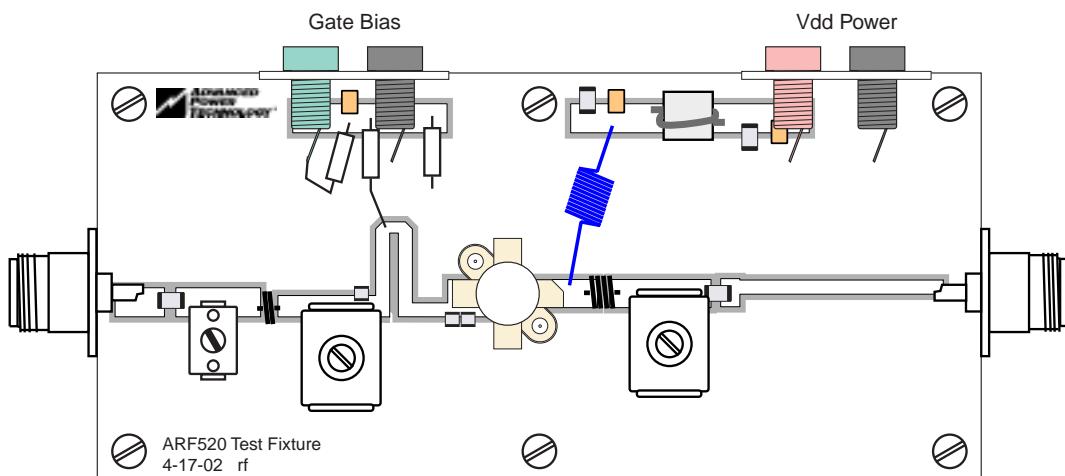
Freq. (MHz)	Z _{in} (Ω)	Z _{OL} (Ω)
2.0	24 - j 4.5	55 - j 4
13.5	8.3 - j 11.6	45 - j 22
27	2.5 - j 7.1	28.7 - j 28
40	1.0 - j 4.2	17.9 - j 26
65	.30 - j 1.1	9.0 - j 20.6
80	.25 + j 0.3	5.8 - j 17
100	.35 + j 1.6	4 - j 14.2

 Z_{in} - Gate shunted with 25Ω $I_{dq} = 50\text{mA}$ Z_{OL} - Conjugate of optimum load for 150 Watts output at $V_{dd} = 125\text{V}$

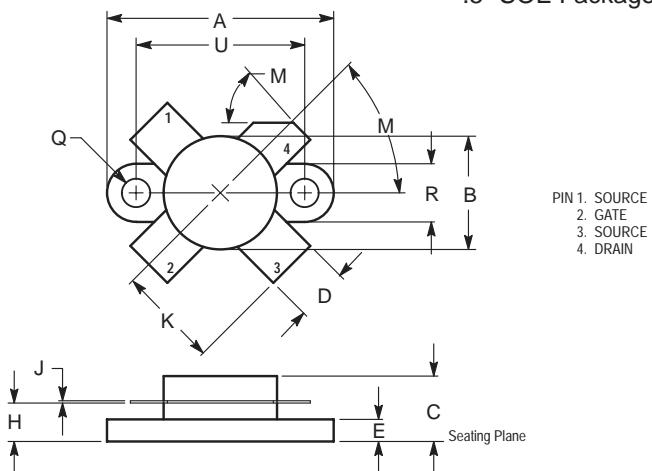
ARF520



C1 - Arco 406 Mica trimmer
 C2 - 220pF Semco metal clad
 C3 - Arco 464 Mica trimmer
 C4 - 820 pF ATC 700B
 C5 - 1000 pF ATC 700B
 C6 - Arco 463 Mica trimmer
 C7-C10 10nF 500V chip
 C11-C13 1nF NPO 500V
 TL1 - .23" x 1.5" stripline
 L1 -- 2t #18 .3" ID .2" L ~50nH
 L2 -- 3t #16 AWG .31" ID .3" L ~65nH
 L3 -- 10t #22 AWG .25 ID ~470nH
 L4 -- VK200-4B ferrite choke ~3uH
 R1-R3 -- 1k Ohm 1/4W Carbon
 DUT = ARF520



.5" SOE Package Outline



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.960	0.990	24.39	25.14
B	0.465	0.510	11.82	12.95
C	0.229	0.275	5.82	6.98
D	0.216	0.235	5.49	5.96
E	0.084	0.110	2.14	2.79
H	0.144	0.178	3.66	4.52
J	0.003	0.007	0.08	0.17
K	0.435		11.0	
M	.45° NOM		.45° NOM	
O	0.115	0.130	2.93	3.30
R	0.246	0.255	6.25	6.47
U	0.720	0.730	18.29	18.54

Controlling Dimension: INCH.

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and mounting surface is beryllium oxide, BeO. Beryllium oxide dust is toxic when inhaled. Care must be taken during handling and mounting to avoid damage to this area. These devices must never be thrown away with general industrial or domestic waste.